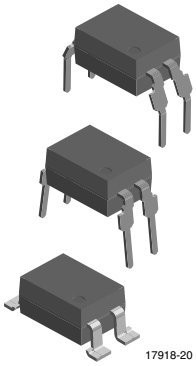
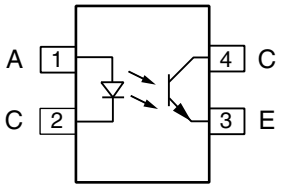
Optocoupler, Phototransistor Output, High Reliability, 5000 V_{RMS}, 110 °C Rated





FEATURES

- Operating temperature from - 55 °C to + 110 °C
- Good CTR linearity depending on forward current
- Isolation test voltage, 5000 V_{RMS}
- High collector emitter voltage, V_{CEO} = 70 V
- Low saturation voltage
- Fast switching times
- Low CTR degradation
- Temperature stable
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode interference immunity
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb-free

e3

RoHS COMPLIANT

GREEN (5-2008)**

Note

** Please see document “Vishay Material Category Policy”: www.vishay.com/doc?99902

DESCRIPTION

The 110 °C rated SFH617A (DIP) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm spacing.

Creepage and clearance distances of > 8.0 mm are achieved with option 6. This version complies with IEC 60950 (DIN VDE 0805) for reinforced insulation up to an operation voltage of 400 V_{RMS} or DC. Specifications subject to change.

APPLICATIONS

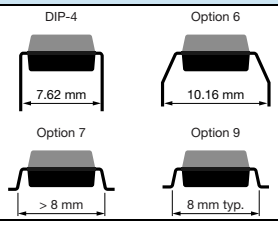
- AC adapter
- SMPS
- PLC
- Factory automation
- Game consoles

AGENCY APPROVALS

- UL1577, file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending) available with option 1
- BSI IEC 60950; IEC 60065
- FIMKO
- CQC (pending)

ORDERING INFORMATION

S	F	H	6	1	7	A	-	#	X	0	#	#	T
PART NUMBER								CTR BIN	PACKAGE OPTION				TAPE AND REEL



AGENCY CERTIFIED/PACKAGE	CTR (%)			
UL, VDE, BSI, FIMKO, cUL	**40 to 80**	**63 to 125**	**100 to 200**	**160 to 320**
DIP-4	SFH617A-1	SFH617A-2	SFH617A-3	SFH617A-4
DIP-4, 400 mil, option 6	SFH617A-1X006	SFH617A-2X006	SFH617A-3X006	SFH617A-4X006
SMD-4, option 7	SFH617A-1X007T	-	SFH617A-3X007T	-
SMD-4, option 9	-	SFH617A-2X009T	-	-
VDE, UL, BSI, FIMKO, cUL	**40 to 80**	**63 to 125**	**100 to 200**	**160 to 320**
DIP-4	SFH617A-1X001	SFH617A-2X001	SFH617A-3X001	SFH617A-4X001
DIP-4, 400 mil, option 6	SFH617A-1X016	SFH617A-2X016	SFH617A-3X016	SFH617A-4X016
SMD-4, option 7	-	SFH617A-2X017T	SFH617A-3X017T (1)	-
SMD-4, option 9	-	SFH617A-2X019T (1)	-	-

Notes

- Additional options may be possible, please contact sales office.

(1) Also available in tubes; do not add T to end.

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
INPUT				
Reverse voltage		V_R	6	V
Forward current		I_F	60	mA
Forward surge current	$t_p \leq 10$ µs	I_{FSM}	2.5	A
LED power dissipation	at 25 °C	P_{diss}	70	mW
OUTPUT				
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Collector peak current	$t_p/T = 0.5$, $t_p \leq 10$ ms	I_{CM}	100	mA
Ouput power dissipation	at 25 °C	P_{diss}	150	mW
COUPLER				
Isolation test voltage (RMS)	t = 1 s	V_{ISO}	5000	V_{RMS}
Isolation resistance	V_{IO} = 500 V, T_{amb} = 25 °C	R_{IO}	$\geq 10^{12}$	Ω
	V_{IO} = 500 V, T_{amb} = 100 °C	R_{IO}	$\geq 10^{11}$	Ω
Operation temperature		T_{amb}	- 55 to + 110	°C
Storage temperature range		T_{stg}	- 55 to + 150	°C
Soldering temperature [1]	2 mm from case, ≤ 10 s	T_{sld}	260	°C

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
INPUT							
Forward voltage	I_F = 60 mA		V_F		1.35	1.65	V
Reverse current	V_R = 6 V		I_R		0.01	10	µA
Capacitance	V_R = 0 V, f = 1 MHz		C_O		13		pF
OUTPUT							
Collector emitter capacitance	V_{CE} = 5 V, f = 1 MHz		C_{CE}		5.2		pF
Collector emitter leakage current	V_{CE} = 10 V	SFH617A-1	I_{CEO}		2	50	nA
		SFH617A-2	I_{CEO}		2	50	nA
		SFH617A-3	I_{CEO}		5	100	nA
		SFH617A-4	I_{CEO}		5	100	nA
COUPLER							
Collector emitter saturation voltage	I_F = 10 mA, f = 1 MHz		V_{CEsat}		0.25	0.4	V
Coupling capacitance			C_C		0.4		pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
I_C/I_F	I_F = 10 mA, V_{CE} = 5 V	SFH617A-1	CTR	40		80	%
		SFH617A-2	CTR	63		125	%
		SFH617A-3	CTR	100		200	%
		SFH617A-4	CTR	160		320	%
	I_F = 1 mA, V_{CE} = 5 V	SFH617A-1	CTR	13	30		%
		SFH617A-2	CTR	22	45		%
		SFH617A-3	CTR	34	70		%
		SFH617A-4	CTR	56	90		%

SWITCHING CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
NON-SATURATED							
Turn-on time	I_F = 10 mA, V_{CC} = 5 V, R_L = 75 Ω		t_{on}		3		µs
Rise time	I_F = 10 mA, V_{CC} = 5 V, R_L = 75 Ω		t_r		2		µs
Turn-off time	I_F = 10 mA, V_{CC} = 5 V, R_L = 75 Ω		t_{off}		2.3		µs
Fall time	I_F = 10 mA, V_{CC} = 5 V, R_L = 75 Ω		t_f		2		µs
Cut-off frequency	I_F = 10 mA, V_{CC} = 5 V		f_{CO}		100		kHz
SATURATED							
Turn-on time	I_F = 20 mA	SFH617A-1	t_{on}		3		µs
	I_F = 10 mA	SFH617A-2	t_{on}		4.2		µs
		SFH617A-3	t_{on}		4.2		µs
	I_F = 5 mA	SFH617A-4	t_{on}		6		µs
Rise time	I_F = 20 mA	SFH617A-1	t_r		2		µs
	I_F = 10 mA	SFH617A-2	t_r		3		µs
		SFH617A-3	t_r		3		µs
	I_F = 5 mA	SFH617A-4	t_r		4.6		µs
Turn-off time	I_F = 20 mA	SFH617A-1	t_{off}		18		µs
	I_F = 10 mA	SFH617A-2	t_{off}		23		µs
		SFH617A-3	t_{off}		23		µs
	I_F = 5 mA	SFH617A-4	t_{off}		25		µs
Fall time	I_F = 20 mA	SFH617A-1	t_f		11		µs
	I_F = 10 mA	SFH617A-2	t_f		14		µs
		SFH617A-3	t_f		14		µs
	I_F = 5 mA	SFH617A-4	t_f		15		µs

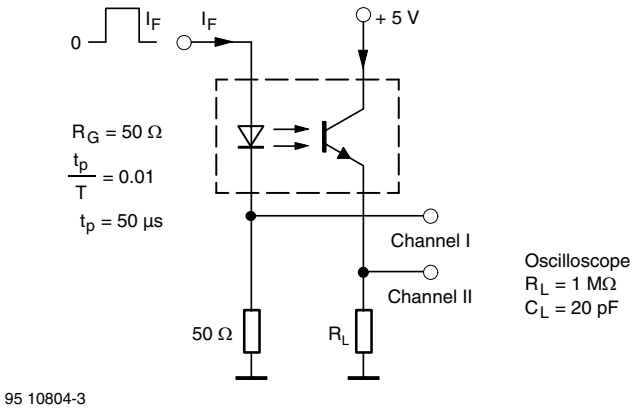


Fig. 1 - Test Circuit, Non-Saturated Operation

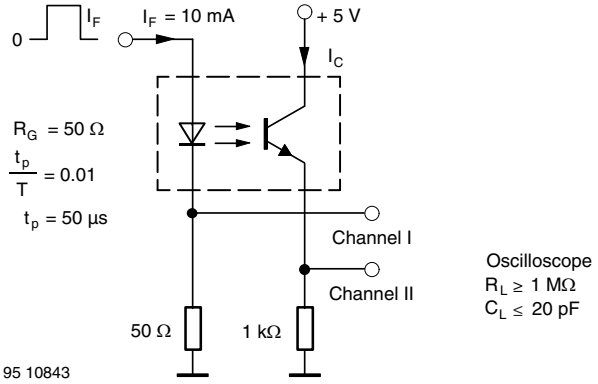


Fig. 2 - Test Circuit, Saturated Operation

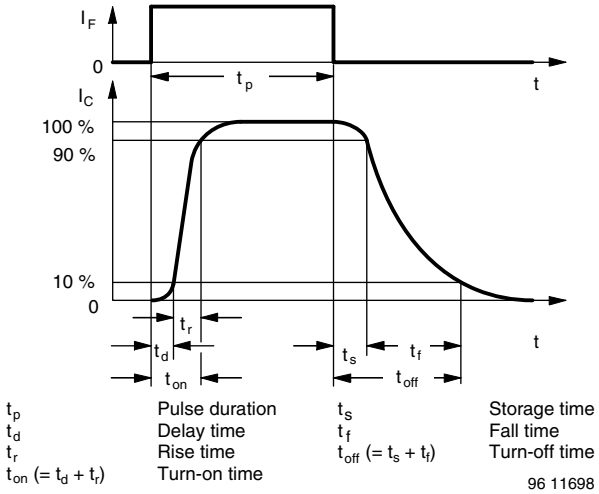


Fig. 3 - Switching Times

SAFETY AND INSULATION RATINGS						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Climatic classification (according to IEC 68 part 1)				55/110/21		
Comparative tracking index		CTI	175		399	
Rated impulse voltage		V_{IOTM}			8	kV
Maximum working voltages	Recurring peak voltage	V_{IORM}			890	V
Forward current		I_{SI}			275	mA
Power dissipation		P_{SO}			400	mW
Safety temperature		T_{SI}			175	°C
Creepage distance			7.0			mm
Clearance distance			7.0			mm
Isolation distance	per IEC 60950 2.10.5.1		0.4			mm

Note

- According to DIN EN 60747-5-2 (VDE 0884). These optocouplers are suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

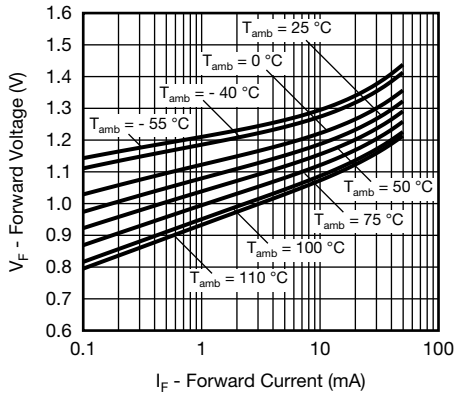


Fig. 4 - Forward Voltage vs. Forward Current

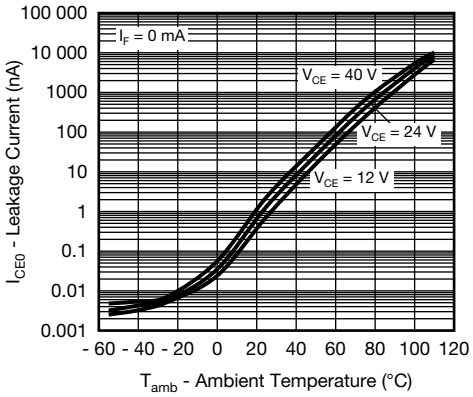


Fig. 7 - Leakage Current vs. Ambient Temperature

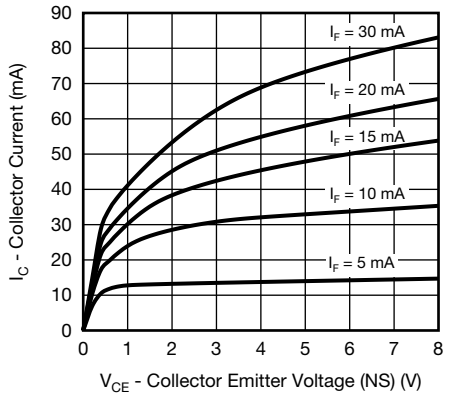


Fig. 5 - Collector Current vs. Collector Emitter Voltage (NS)

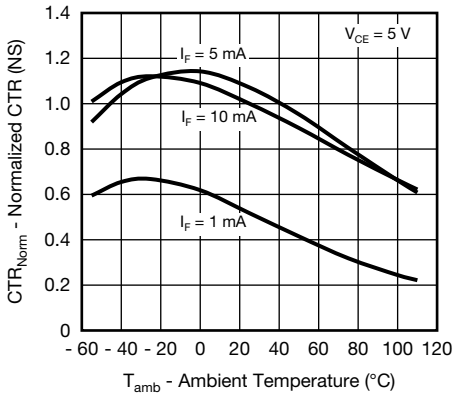


Fig. 8 - Normalized CTR (NS) vs. Ambient Temperature

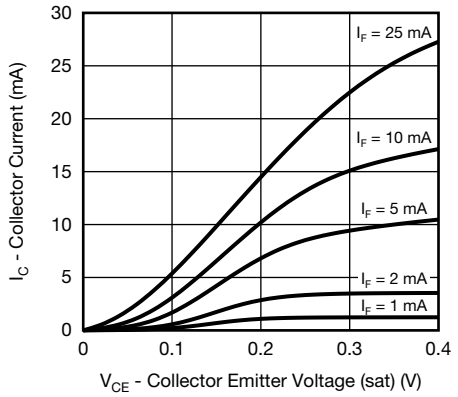


Fig. 6 - Collector Current vs. Collector Emitter Voltage (sat)

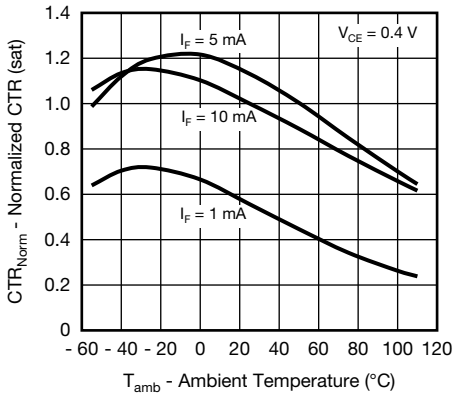


Fig. 9 - Normalized CTR (sat) vs. Ambient Temperature

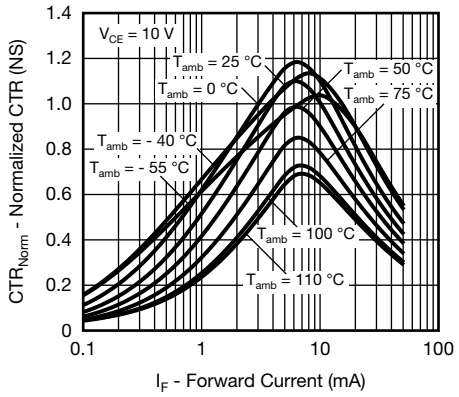


Fig. 10 - Normalized CTR (NS) vs. Forward Current

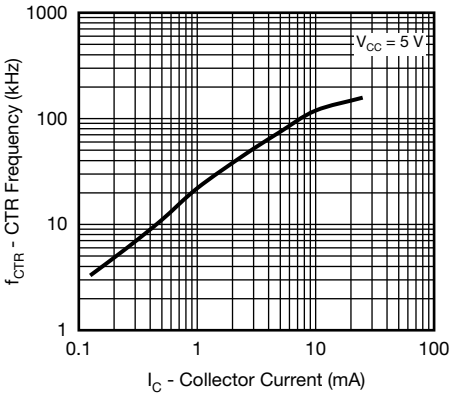


Fig. 13 - CTR Frequency vs. Collector Current

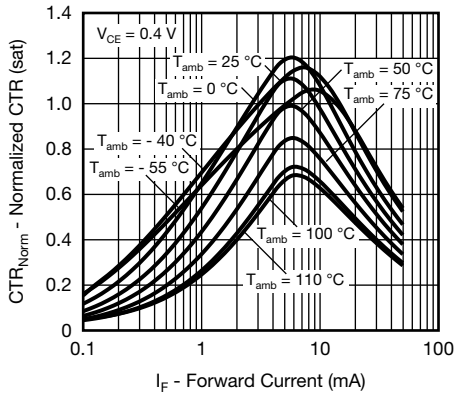


Fig. 11 - Normalized CTR (sat) vs. Forward Current

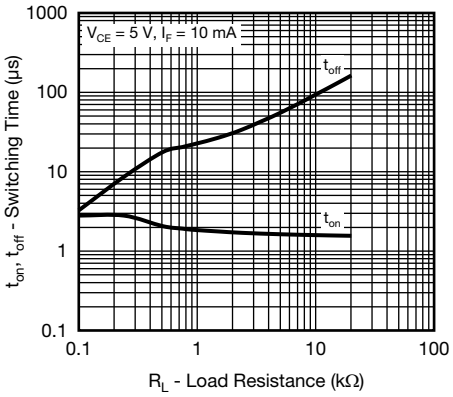


Fig. 14 - Switching Time vs. Load Resistance

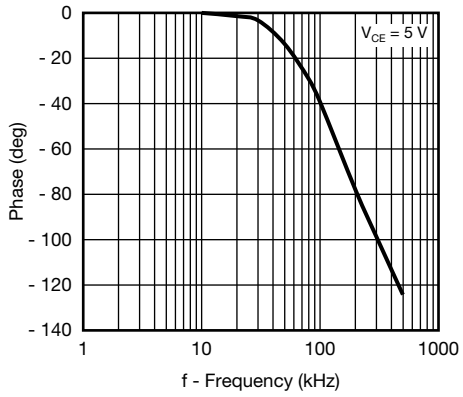
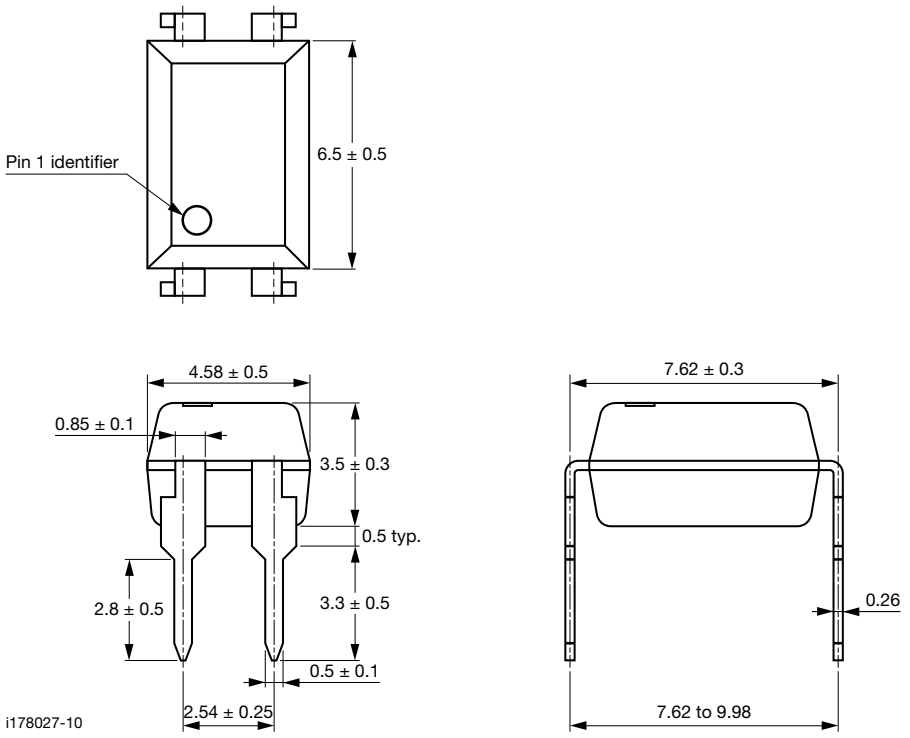
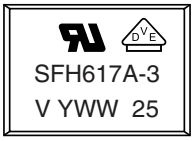


Fig. 12 - CTR Frequency vs. Phase Angle

PACKAGE DIMENISONS in millimeters



PACKAGE MARKING



Notes

- VDE logo is only marked on option 1 parts. Option information is not marked on the part.
- Tape and reel suffix (T) is not part of the package marking.

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.